

## TMR Magnetic Field Sensor CYMR2102

The CYMR2102 linear sensor utilizes a unique push-pull Wheatstone bridge composed of four unshielded TMR sensor elements. The unique bridge design provides a high sensitivity differential output that is linearly proportional to a magnetic field applied parallel to the surface of the sensor package, and it provides superior temperature compensation of the output. The CYMR2102 is available in two packages: **SOP8** 6x5x1.5mm (P/N:CYMR2102P), or **DFN8** 3x3x0.75mm (P/N:CYMR2102D).

### Features and Benefits

- Tunneling Magnetoresistance (TMR) Technology
- High Sensitivity
- Large Dynamic Range
- Very Low Power Consumption
- Excellent Thermal Stability
- Very Low Hysteresis
- Compatible with Wide Range of Supply Voltages



SOP8

### Applications

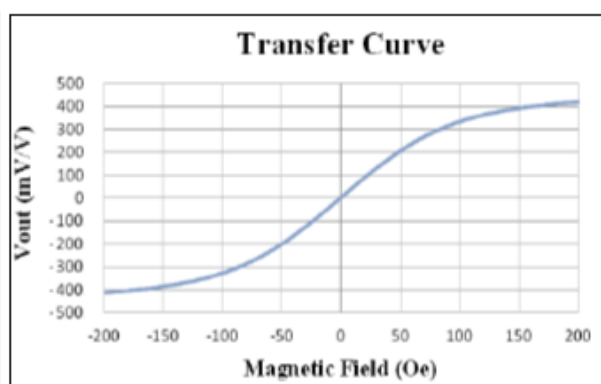
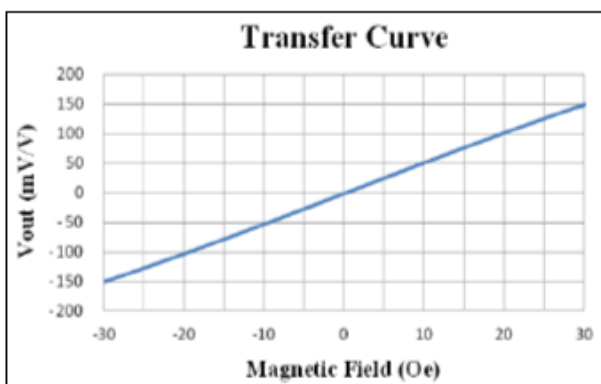
- Magnetic Field Sensing
- Current Sensors
- Industrial Flow Meters
- Displacement Sensing
- Rotary Position Sensors



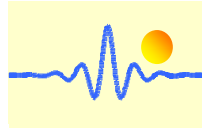
DFN8

### Transfer Curve

The following figure shows the response of the CYMR2102 to an applied magnetic field in the range of  $\pm 30$  Oe (left) and  $\pm 200$  Oe (right) when the CYMR2102 is biased at 1V. At low fields the CYMR2102 response is highly linear, and it is not harmed when the sensor is driven into saturation.



Oe (Oersted) = 1 Gauss in air = 0.1 millitesla = 79.8 A/m.



## Absolute Maximum Ratings

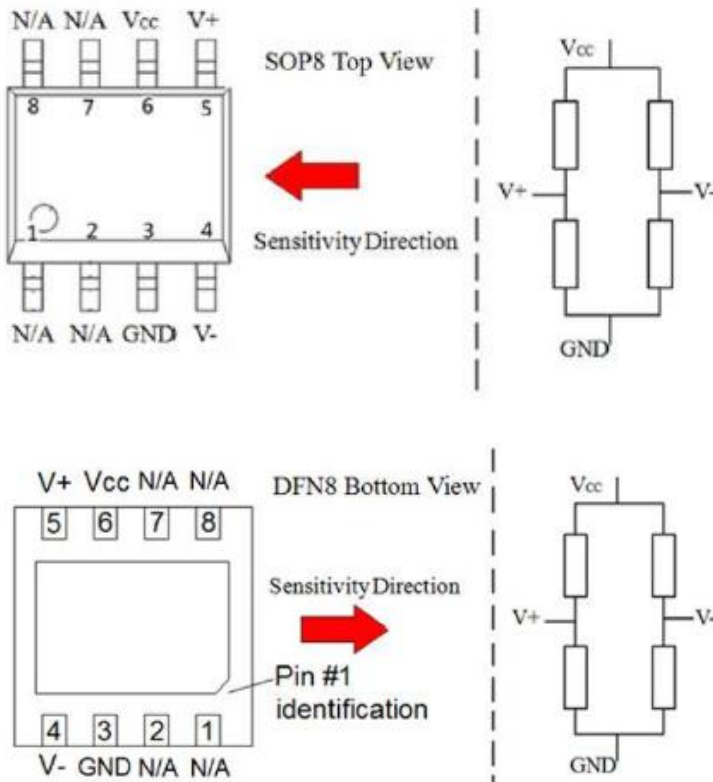
Parameter	Symbol	Limit	Unit
Supply Voltage	$V_{CC}$	7	V
Reverse Supply Voltage	$V_{RCC}$	-7	V
Max Exposed Field	$H_E$	1000	Oe
ESD Voltage	$V_{ESD}$	4000	V
Operating Temperature	$T_A$	-40~125	°C
Storage Temperature	$T_{stg}$	-50 ~150	°C

## Specification ( $V_{CC}=1.0V, T_A=25^\circ C, \text{Differential Output}$ )

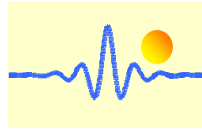
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Supply Voltage	$V_{CC}$	Operating		1	7	V
Supply Current (SOP8 / DFN8)	$I_{CC}$	Output Open		11 / 22		$\mu A$
Resistance(SOP8 / DFN8)	R			90 /45		k $\Omega$
Sensitivity	S	Fit @ $\pm 30Oe$		4.9		mV/V/Oe
Saturation Field	$H_{sat}$			$\pm 90$		Oe
No-linearity	NL	Fit @ $\pm 30Oe$		1.0		%FS
Offset voltage	$V_{os}$		-20		20	mV/V
Hysteresis	Hys	Fit @ $\pm 30Oe$		0.1	0.2	Oe
Temperature Coefficient of resistance	TCR	H=0		-820		ppm/°C
Temperature Coefficient of Sensitivity	TCS			-1160		ppm/°C

## Pin Configuration

(Arrow indicates direction of applied field that generates a positive output voltage after a SET pulse.)

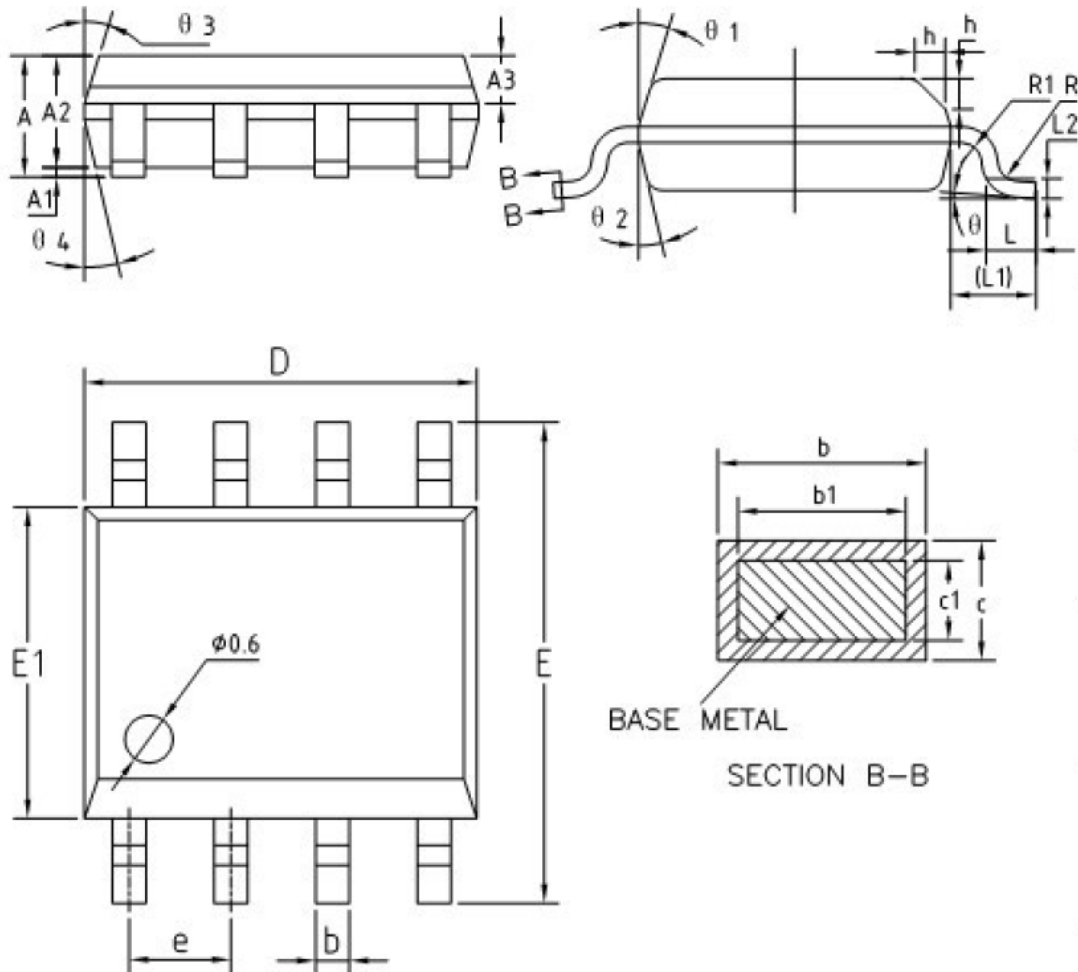


Pin No.	Pin Name	Pin function
1,2,7,8	N/A	Not connected
3	GND	Ground
4	V-	Analog Differential Output 2
5	V+	Analog Differential Output 1
6	Vcc	Supply Voltage



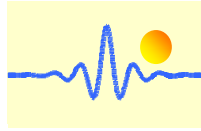
## Package Information

### SOP8 package drawing

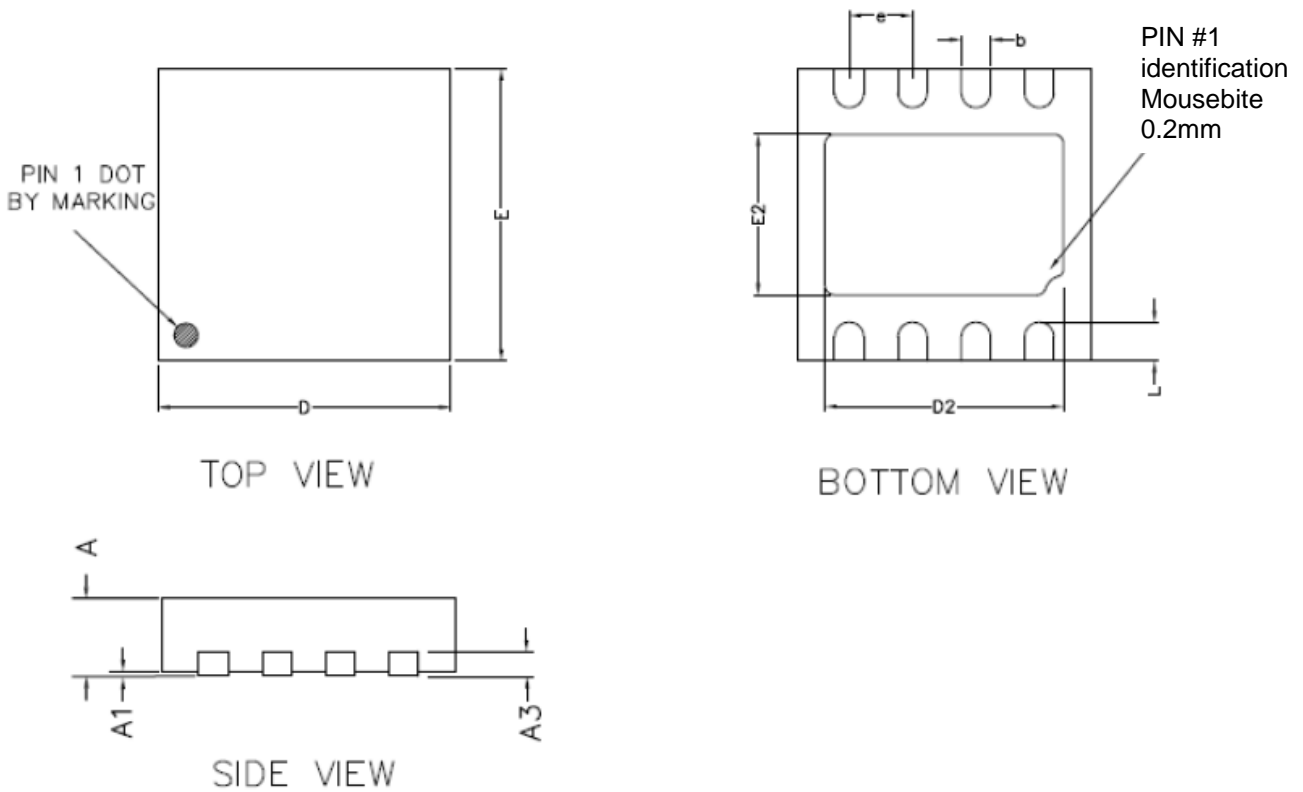


### Common Dimensions (in mm)

Symbol	Min.	Typ.	Max.	Symbol	Min.	Typ.	Max.
<b>A</b>	1.35	1.55	1.75	<b>A1</b>	0.10	0.15	0.25
<b>A2</b>	1.25	1.40	1.65	<b>A3</b>	0.50	0.60	0.70
<b>b</b>	0.38	0.45	0.51	<b>b1</b>	0.37	0.42	0.47
<b>c</b>	0.18	0.22	0.25	<b>c1</b>	0.17	0.20	0.23
<b>D</b>	4.80	4.90	5.00	<b>E</b>	5.80	6.00	6.20
<b>E1</b>	3.80	3.90	4.00	<b>e</b>	1.17	1.27	1.37
<b>L</b>	0.45	0.60	0.80	<b>L1</b>	1.04 REF		
<b>L2</b>	0.25 BSC			<b>R</b>	0.07	-	-
<b>R1</b>	0.07	-	-	<b>h</b>	0.30	0.40	0.50
<b>θ</b>	0°	4°	8°	<b>θ1</b>	15°	17°	19°
<b>θ2</b>	11°	13°	15°	<b>θ3</b>	15°	17°	19°
<b>θ4</b>	11°	13°	15°				

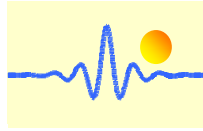


DFN8 package drawing



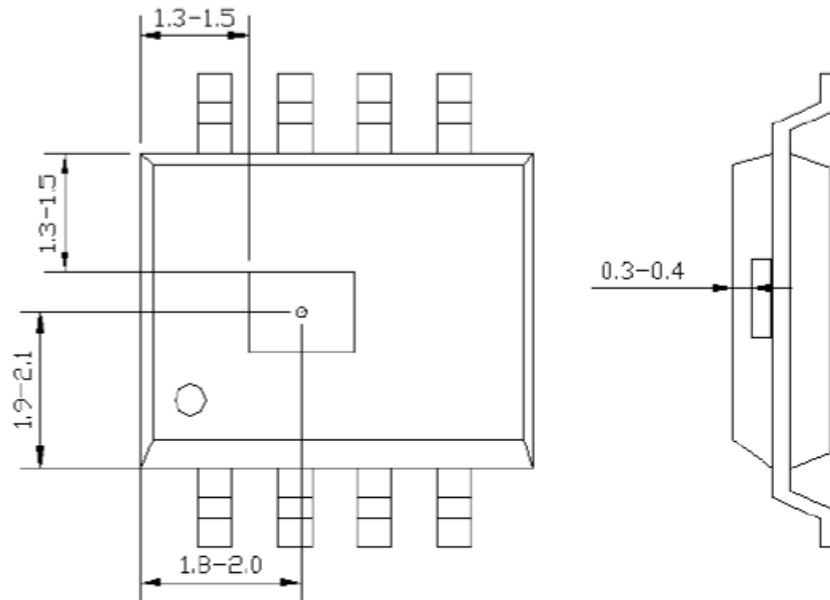
Common Demensions (in mm)

Symbol	Min.	Typ.	Max.
<b>A</b>	0.70	0.75	0.80
<b>A1</b>	0.00	-	0.05
<b>A3</b>	0.20 REF		
<b>D</b>	2.95	3.00	3.05
<b>E</b>	2.95	3.00	3.05
<b>b</b>	0.25	0.30	0.35
<b>L</b>	0.30	0.40	0.50
<b>D2</b>	2.30	2.45	2.55
<b>E2</b>	1.50	1.65	1.75
<b>e</b>	0.65 BSC		

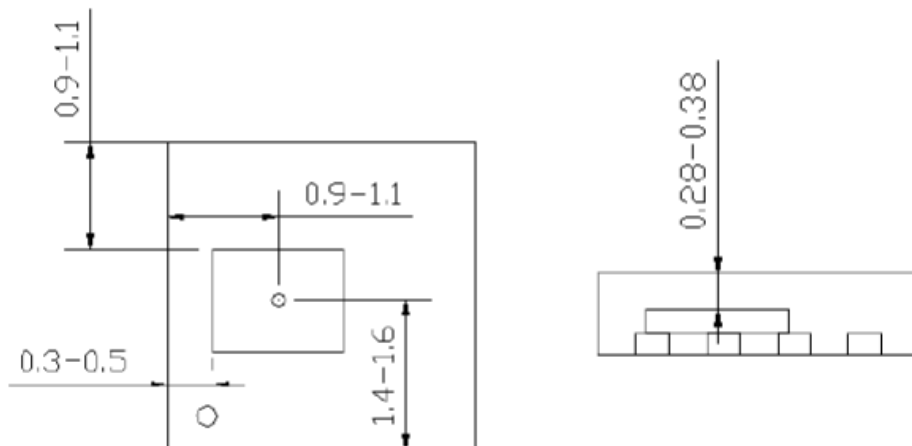


## TMR Sensor Position

Top view and side view (unit: mm)



SOP8 Package



DFN8 Package